

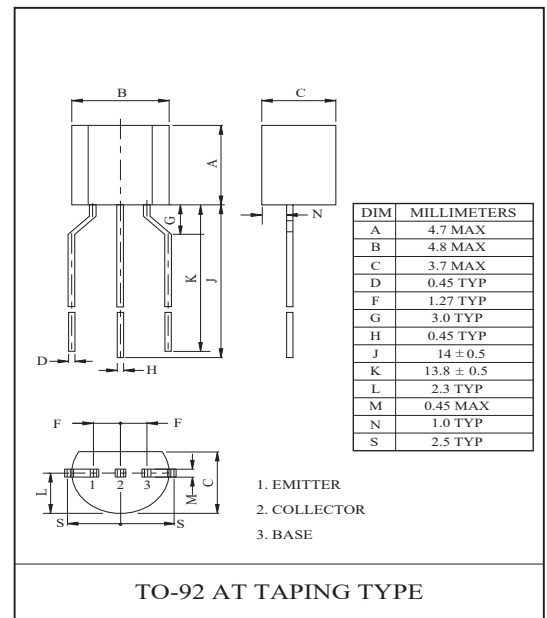
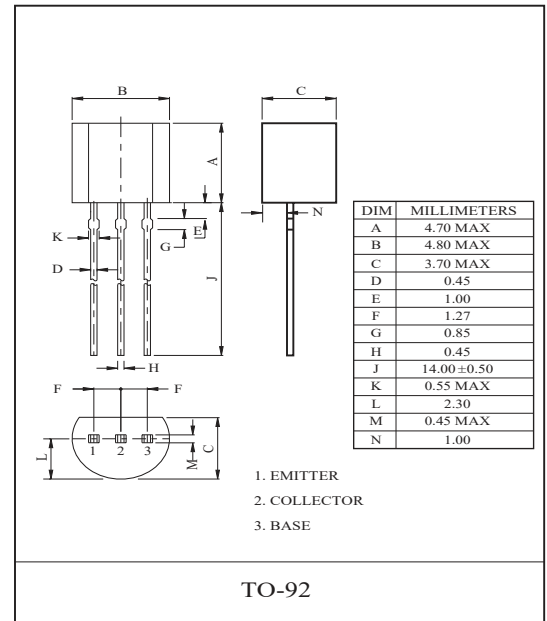
HIGH CURRENT APPLICATION.

### FEATURES

- Complementary to KTC3210.

### MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CBO}$	-30	V
Collector-Emitter Voltage	$V_{CEO}$	-30	V
Emitter-Base Voltage	$V_{EBO}$	-5	V
Collector Current	$I_C$	-2	A
Emitter Current	$I_E$	2	A
Collector Power Dissipation	$P_C$	625	mW
Junction Temperature	$T_j$	150	°C
Storage Temperature Range	$T_{stg}$	-55 ~ 150	°C



### ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB}=-30V, I_E=0$	-	-	-100	nA
Emitter Cut-off Current	$I_{EBO}$	$V_{EB}=-5V, I_C=0$	-	-	-100	nA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=-10mA, I_B=0$	-30	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_C=-1mA, I_C=0$	-5	-	-	V
DC Current Gain	$h_{FE}$ (Note)	$V_{CE}=-2V, I_C=-500mA$	100	-	320	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-1.5A, I_B=-0.03A$	-	-	-2.0	V
Base-Emitter Voltage	$V_{BE}$	$V_{CE}=-2V, I_C=-500mA$	-	-	-1.0	V
Transition Frequency	$f_T$	$V_{CE}=-2V, I_C=-500mA$	-	120	-	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB}=-10V, I_E=0, f=1MHz$	-	48	-	pF

Note :  $h_{FE}$  Classification 0:100 ~ 200, Y:160 ~ 320

